NSN 5961-01-215-7484

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-215-7484 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **End Application:** Bomb scoring radar system an/tpq-43; helicopter, lamps mark iii, sh-60b **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 500.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn; weapon system essential **Test Data Document:** 12115-sc5961-0070 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

N/a

Unit Of Measure:

2 pin and 1 case Shelf Life:

Terminal Type And Quantity:

NSN 5961-01-215-7484

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

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